## **606 ELECTRONICS** (FINAL)

- 1. Inductor is ..... element.
  - (A) active
  - (B) passive
  - (C) linear
  - (D) polar
- Find the unknown resistance value in given circuit. 2.



- (A) 10.2 Ω
- (B) 11.7 Ω
- 10.5 Ω (C)
- (D) 11.5 Ω
- The diffused impurities with ..... valence electrons are 3. called donor atoms.
  - (A) 4 3 **(B)** 5 (C) (D) 0

4.

- What is the range of the operating voltage level for LEDs?
  - (A) 5-12 mV
  - (B) 1.7-3.3 V
  - (C) 5-12 V
  - (D) 20-25 V

- 5. Calculate the power dissipation of a diode having  $I_d = 40$  Ma.
  - (A) 28 mW
  - (B) 28 W
  - (C) 280 mW
  - (D) 400 mW

6. For a MOSFET  $V_{gs} = 3 V$ ,  $I_{ds} = 5 A$  and  $I_d = 2 A$ . Find the pinch of voltage  $V_p$ .

- (A) 4.08
- (B) 8.16
- (C) 16.32
- (D) 0

7. The crystal Oscillator frequency is very stable due to ..... of the Crystal.

- (A) rigidity
- (B) vibrations
- $(C) \quad low \ Q$
- $(D) \quad high \ Q$
- 8. In an LC Oscillator, if the value of L is increased four times, the frequency of oscillations is
  - (A) 4f
  - (B) 2f
  - (C)  $\frac{1}{4}$
  - (D)  $\frac{f}{2}$
- 9. 2's complement of (11001011)<sub>2</sub> is
  - (A) 01010111
  - (B) 11010100
  - (C) 00110101
  - (D) 11100010
- 10. MOS families includes
  - (A) PMOS and NMOS
  - (B) CMOS and NMOS
  - (C) PMOS, NMOS and CMOS
  - (D) EMOS, NMOS and PMOS

- 11. Propagation delay is defined as
  - (A) the time taken for the output of a gate to change after the inputs have changed
  - (B) the time taken for the input of a gate to change after the outputs have changed
  - (C) the time taken for the input of a gate to change after the intermediates have changed
  - (D) the time taken for the output of a gate to change after the intermediates have changed
- 12. When 8051 wakes up then 0x00 is loaded to which register?
  - (A) DPTR
  - (B) SP
  - (C) PC
  - (D) PSW

13. An example of a discrete set of information/system is

- (A) the trajectory of the Sun
- (B) data on a CD
- (C) universe time scale
- (D) movement of water through a pipe
- 14. AM radio signal is an example for
  - (A)  $y(t) = a \times x(t)$
  - (B)  $y(t) = x_1(t) + x_2(t)$
  - (C) y(t) = -x(t)
  - (D)  $y(t) = x_1(t) \times x_2(t)$
- 15. What provides a periodic voltage waveform?
  - (A) Sweep generator
  - (B) Voltmeter
  - (C) Oscillator
  - (D) Amplifier
- 16. Lumped parameter delay line consists of
  - (A) RC networks
  - (B) RL networks
  - (C) LC networks
  - (D) Resistive networks

### 17. A trigger circuit is

- (A) is used for triggering the input
- (B) is used for triggering the output
- (C) used with time base generator
- (D) used as a oscillator

18. Resistance of a metallic conductor is given by

(A) 
$$R = \frac{l}{A}$$
  
(B)  $R = \frac{\rho}{A}$   
(C)  $R = \frac{\rho l}{A}$   
(D)  $R = \frac{l}{A}$ 

- 19. Avalanche photodiodes based on HgCdTe are used for ..... in both the near and far infrared.
  - (A) dispersion
  - (B) dislocation
  - (C) ionization
  - (D) array applications

A

- 20. Mechanical transducers cause
  - (A) power loss
  - (B) hysteresis loss
  - (C) eddy current loss
  - (D) frictional loss
- 21. Relation between temperature and resistance of a conductor is

(A) 
$$R_t = R_{ref} [1+t]$$

- (B)  $R_t = R_{\text{ref}} [1 + \alpha \Delta t]$
- (C)  $R_t = R_{ref} [1 \alpha t]$
- (D)  $R_t = R_{ref} [1-t]$

- 22. Platinum is used for industrial applications because
  - (A) it is cheap
  - (B) it is available readily
  - (C) it is a noble metal
  - (D) it gives accurate measurements
- 23. Reluctance of a coil is given by the relation

(A) 
$$S = \frac{l}{A}$$
  
(B)  $S = \frac{l}{\mu}$   
(C)  $S = \frac{a}{\lambda}$ 

(C) 
$$S = \frac{\mu A}{\mu A}$$
  
(D)  $S = \frac{l}{\mu A}$ 

- 24. Which of the following is used to establish a fixed level of current or voltage in a transistor?
  - (A) Biasing
  - (B) Loading
  - (C) Load line
  - (D) Coupling
- 25. Which of the following represents common-emitter small signal input resistance?
  - (A)  $h_{ie}$
  - (B)  $h_{fe}$
  - (C) *hib*
  - (D) *h*<sub>oe</sub>
- 26. The ear is not sensitive to ..... distortion.
  - (A) frequency
  - (B) amplitude
  - (C) harmonic
  - (D) phase

- 27. The collector current in a common base configuration is equal to
  - (A) alpha times emitter current plus leakage current
  - (B) alpha times base current plus leakage current
  - (C) beta times emitter current plus leakage current
  - (D) beta times collector current plus leakage current

28. Which is **NOT** a basic BJT amplifier configuration?

- (A) Common-drain
- (B) Common-base
- (C) Common-emitter
- (D) Common-collector

29. The bandwidth of a single stage amplifier is ..... that of multistage amplifier.

- (A) equal to
- (B) less than
- (C) more than
- (D) independent
- 30. Which configuration has the lowest current gain?
  - (A) Common-base
  - (B) Common-collector
  - (C) Common-emitter
  - (D) Emitter follower
- 31. An ammeter's ideal resistance should be
  - (A) zero
  - (B) unity
  - (C) infinite
  - (D) the same with the circuit's resistance
- 32. The input impedance of an amplifier ..... when negative voltage feedback is applied.
  - (A) decreases
  - (B) becomes zero
  - (C) increases
  - (D) is unchanged

- 33. A semiconductor has ..... temperature coefficient of resistance.
  - (A) positive
  - (B) zero
  - (C) negative
  - (D) None of the above

34. The resistivity of a pure silicon is about

- (A)  $100 \Omega$  cm
- (B)  $6000 \Omega$  cm
- (C)  $3 \times 10^5 \Omega m$
- (D)  $6 \times 10^{-8} \Omega \text{ cm}$

35. When a pure semiconductor is heated, its resistance

- (A) goes up
- (B) goes down
- (C) remains the same
- (D) can't say
- 36. The strength of a semiconductor crystal comes from
  - (A) forces between nuclei
  - (B) forces between protons
  - (C) electron-pair bonds
  - (D) None of the above
- 37. A hole in a semiconductor is defined as
  - (A) a free electron
  - (B) the incomplete part of an electron pair bond
  - (C) a free proton
  - (D) a free neutron

38. As the doping to a pure semiconductor increases, the bulk resistance of the semiconductor

- (A) remains the same
- (B) increases
- (C) decreases
- (D) None of the above

- 39. In a semiconductor, current conduction is due to
  - (A) only holes
  - (B) only free electrons
  - (C) holes and free electrons
  - (D) None of the above
- 40. In the depletion region of a p-n junction, there is a shortage of
  - (A) acceptor ions
  - (B) holes and electrons
  - (C) donor ions
  - (D) None of the above
- 41. A p-n junction acts as a
  - (A) controlled switch
  - (B) bidirectional switch
  - (C) unidirectional switch
  - (D) None of the above
- 42. The leakage current across a p-n junction is due to
  - (A) minority carriers
  - (B) majority carriers
  - (C) junction capacitance
  - (D) None of the above
- 43. With forward bias to a p-n junction, the width of depletion layer
  - (A) decreases
  - (B) increases
  - (C) remains the same
  - (D) None of the above

44. At absolute temperature, an intrinsic semiconductor has

- (A) a few free electrons
- (B) many holes
- (C) many free electrons
- (D) no holes or free electrons

- 45. An ac voltage source of  $2\sin t$  V is connected in series with a dc voltage source of 5 V. If a PMMC instrument is connected in parallel to this combination then the reading of meter will be equal to
  - (A) 7 V
  - (B) 5 V
  - (C) 5.2 V
  - (D) 25 V
- 46. A PMMC instrument can be used as ammeter and as voltmeter with the help of
  - (A) a low resistance shunt, a low series resistance
  - (B) a low resistance shunt, a high series resistance
  - (C) a high series resistance, a low resistance shunt
  - (D) a low series resistance, a high shunt resistance
- 47. The given figure shows the Wheatstone bridge method for measurement of unknown resistance (R). The balanced equation for Wheatstone bridge is given by



- 48. In terms of the division on screen, the voltage of the waveform in CRO is
  - (A) average voltage
  - (B) RMS voltage
  - (C) peak to peak voltage
  - (D) maximum voltage
- 49. If the two input waveforms are of equal amplitude and 90-degree phase difference is applied to the CRO then the Lissajous patterns obtained will be
  - (A) straight line tilted at 45 degree with respect to X-axis
  - (B) circle
  - (C) ellipse
  - (D) vertical straight line
- 50. The ripple factor of a bridge rectifier is
  - (A) 0.482
  - (B) 0.812
  - (C) 1.11
  - (D) 1.21
- 51. A half-wave rectifier is equivalent to a
  - (A) a clamper circuit
  - (B) a clipper circuit
  - (C) a clamper circuit with negative bias
  - (D) a clamper circuit with positive bias
- 52. The basic reason why a full-wave rectifier has a twice the efficiency of a half-wave rectifier is that
  - (A) it makes use of transformer
  - (B) its ripple factor is much less
  - (C) it utilizes both half-cycle of the input
  - (D) its output frequency is double the line frequency
- 53. A certain inverting amplifier has a closed-loop voltage gain of 25. The Op-amp has an open-loop voltage gain of 100,000. If an Op-amp with an open-loop voltage gain of 200,000 is substituted in the arrangement, the closed-loop gain
  - (A) doubles
  - (B) drops to 12.5
  - (C) remains at 25
  - (D) increases slightly

54. What is the Fermi energy of a n-type semiconductor?

(A) 
$$E$$
  
(B)  $E_F = \frac{\left(E_c + E_v\right)}{2}$   
(C)  $E_F = \frac{\left(E_c + E_d\right)}{2}$   
(D)  $E_F = \frac{\left(E_v + E_a\right)}{2}$ 

55. The drift velocity of electrons is of the order of

- (A)  $1 \text{ ms}^{-1}$
- (B)  $10^{-3} \text{ ms}^{-1}$
- (C)  $10^6 \text{ ms}^{-1}$
- (D)  $3 \times 10^8 \text{ ms}^{-1}$
- 56. The potential difference of an energy source that provides 50 mJ of energy for every micro coulomb of charge that flows is
  - (A) 5 V
  - $(B) \quad 50 \ V$
  - (C) 500 V
  - (D) 50 kV

57. The example of non-ohmic resistance is

- (A) copper wire
- (B) carbon wire
- (C) aluminium wire
- (D) tungsten wire
- 58. The internal resistance of a cell of emf 2 V is 0.1  $\Omega$ . It is connected to a resistance of 3.9  $\Omega$ . The voltage across the cell is
  - (A) 0.5 V
  - (B) 1.95 V
  - (C) 1.9 V
  - (D) 2 V

59. Find the Thevenin's equivalent circuit to the left of terminals x-y in figure.



- 60. Two charges  $+3 \mu C$  and  $-12 \mu C$  are separated by a distance of 0.4 m. Where should a third change of  $+3 \mu C$  be placed from  $+3 \mu C$  so that it experiences zero force?
  - (A) 0.4 m
  - (B) 0.2 m
  - (C) 0.3 m
  - (D) 0.1 m
- 61. Electrons are caused to fall through a potential difference of 1500 V. If they were initially at rest, their final speed is
  - (A)  $2.3 \times 10^3 \text{ ms}^{-1}$
  - (B)  $2.3 \times 10^7 \text{ ms}^{-1}$
  - (C)  $4.6 \times 10^4 \text{ ms}^{-1}$
  - (D)  $0.23 \times 10^{12} \text{ ms}^{-1}$
- 62. Two parallel metal plated maintained at a potential difference of 1000 V are separated by 0.02 m. An electron is placed between the two plates. The force experienced by the electron is
  - (A)  $1.6 \times 10^{-19}$  N
  - (B)  $8 \times 10^{-15}$  N
  - (C) 1000 N
  - (D) None of the above

- 63. An electric dipole is placed in a non-uniform electric field. It experiences
  - (A) a force but no torque
  - (B) a force and a torque
  - (C) a torque but no force
  - (D) neither a force nor a torque
- 64. A circuit with a resistor, indicator and capacitor in series is resonant at frequency  $f_0$ . If all component values are now doubled, what is new resonant frequency?
  - (A)  $2f_0$
  - (B) Still  $f_0$
  - (C)  $\frac{f_0}{4}$ (D)  $\frac{f_0}{2}$
- 65. The source of the magnetic field is
  - (A) an isolated magnetic pole
  - (B) static electric charge
  - (C) magnetic substances
  - (D) current loop
- 66. Figure shows the magnetic field around the conductor. Direction of current flowing



- (A) from right to left
- (B) from left to right
- (C) can be either of above
- (D) data incomplete

67. Which end of the coil shown in the figure is the North Pole?



- (A) Left
- (B) Right
- (C) Neither left nor right
- (D) Data incomplete

68. Deflection in a Galvanometer falls from 50 divisions to 20 divisions when a 12  $\Omega$ Shunt is applied. Galvanometer resistance is

- (A) 18 Ω
- (B) 6Ω
- $(C) \quad 9 \; \Omega$
- $(D) \quad 24 \; \Omega$
- 69. At low frequencies, the material used for transformer cores is
  - (A) copper
  - (B) silicon iron
  - (C) soft iron
  - (D) None of the above
- 70. The minimum relative permeability of the material can be
  - (A) 1
  - (B) slightly less than 1
  - (C) 0.005
  - (D) None of the above

71. An air-cored choke is used for ..... applications.

- (A) radio frequency
- (B) audio frequency
- (C) power frequency
- (D) None of the above

In figure, the maximum inductance between the coils is 72.



- 73.
  - (A) directly proportional to
  - (B) inversely proportional to
  - (C) directly proportional to square of
  - (D) inversely proportional to square of

74. If the frequency of the flux is increased two times, the eddy current power loss is

- (A) increased two times
- decreased two times (B)
- (C) increased four times
- (D) decreased four times

A sinusoidal current has a magnitude of 3 A at 120°. Its maximum value will be 75.

(A) 
$$\sqrt{3}$$
 A  
(B)  $\frac{\sqrt{3}}{2}$  A  
(C)  $2\sqrt{3}$  A  
(D) 6 A

- 76. An alternating voltage is given by  $v = 100 \sin 314t$  volts. Its average value will be
  - (A) 70.7 V
  - (B) 50 V
  - (C) 63.7 V
  - (D) 100 V
- 77. When a 15 V square wave is connected across a 50 V a.c voltmeter, it will read
  - (A) 15 V
  - (B)  $15 \times \sqrt{2}$  V

(C) 
$$\frac{15}{\sqrt{2}}$$
 V

- (D) None of the above
- 78. A capacitor is perfect insulator for
  - (A) alternating current
  - (B) direct current
  - (C) direct as well as alternating current
  - (D) None of the above
- 79. Power absorbed in the pure inductive circuit is zero because
  - (A) reactive component of current is zero
  - (B) active component of current is maximum
  - (C) power factor of the circuit is zero
  - (D) reactive and active components of current cancel out
- 80. A pure inductor is connected to an alternating voltage source. If both the voltage and the frequency are doubled, the circuit current
  - (A) becomes double
  - (B) is halved
  - (C) becomes three times
  - (D) no change

- 81. The register in the 8085 A that is used to keep track of the memory address of the next op-code to be run in the program is the
  - (A) stack pointer
  - (B) program counter
  - (C) instruction pointer
  - (D) accumulator
- 82. The contents of the accumulator after this operation will be

#### MOV A,#0BH

#### ANL A,#2CH

- (A) 11010111
- (B) 11011010
- (C) 00001000
- (D) 00101000
- 83. The small extremely fast, RAM's are called as
  - (A) cache
  - (B) heaps
  - (C) accumulators
  - (D) stacks
- 84. Interrupts are provided primarily as a way to
  - (A) improve processor utilization
  - (B) improve processor execution
  - (C) improve processor control
  - (D) improve processor speed

## 85. Mixing is used in communication to

- (A) raise the carrier frequency
- (B) lower the carrier frequency
- (C) to altered the deviation
- (D) to change the carrier frequency to any required value
- 86. Most of the amplification in a superhetrodyne receiver occurs at ...... stage.
  - (A) IF
  - (B) RF amplifier
  - (C) Audio amplifier
  - (D) Detector

- 87. In a pure inductive circuit if the supply frequency is reduced to  $\frac{1}{2}$ , the current will
  - (A) be reduced by half
  - (B) be doubled
  - (C) be four times as high
  - (D) be reduced to one fourth

88. In a parallel R-C circuit, the current always ..... the applied voltage.

- (A) lags
- (B) leads
- (C) remains in phase with
- (D) None of the above

89. Which transistor bias circuit arrangement provides good stability using negative feedback from collector to base?

- (A) Base bias
- (B) Collector-feedback bias
- (C) Voltage-divider bias
- (D) Emitter bias
- 90. For full-wave rectified sine wave, rms value is



- 91. When transistors are used in digital circuits they usually operate in the
  - (A) active region
  - (B) breakdown region
  - (C) saturation and cutoff regions
  - (D) linear region

- 92. Which among the below assertions is **NOT** a relevant property of CE amplifier?
  - (A) High voltage gain
  - (B) High current gain
  - (C) High input resistance
  - (D) High output resistance
- 93. The SI units of transconductance is
  - (A) Ampere/Volt
  - (B) Volt/Ampere
  - (C) Ohm
  - (D) Siemens
- 94. Field effect transistor's conductivity is regulated by
  - (A) input current
  - (B) output current
  - (C) terminal voltage
  - (D) supply voltage
- 95. In FET, which voltage increases the channel size?
  - (A) Negative Vgs
  - (B) Positive Vgs
  - (C) Negative Vds
  - (D) Positive Vds
- 96. Choose the correct statement
  - (A) MOSFET is a unipolar, voltage controlled, two terminal device
  - (B) MOSFET is a bipolar, current controlled, three terminal device
  - (C) MOSFET is a unipolar, voltage controlled, three terminal device
  - (D) MOSFET is a bipolar, current controlled, two terminal device

## 97. Which factor determines the output voltage of an op-amp?

- (A) Positive saturation
- (B) Negative saturation
- (C) Both positive and negative saturation voltage
- (D) Supply voltage

- 98. The resolution of an n bit DAC with a maximum input of 5 V is 5 mV. The value of n is
  - (A) 8
  - (B) 9
  - (C) 10
  - (D) 11

99. Decimal 43 in hexadecimal and BCD number system is respectively ..... and .....

- (A) B2 and 01000011
- (B) 2B and 01000011
- (C) 2B and 00110100
- (D) B2 and 01000100

100. The basic storage element in a digital system is

- (A) flipflop
- (B) counter
- (C) multiplexer
- (D) encoder

101. Which device has one input and many outputs?

- (A) Multiplexer
- (B) Demultiplexer
- (C) Counter
- (D) Flipflop

102. When a differential amplifier is operated single-ended

- (A) the output is grounded
- (B) one input is grounded and signal is applied to the other
- (C) both inputs are connected together
- (D) the output is not inverted

### 103. For an Op-Amp, the differential gain is

- (A) very high
- (B) very low
- (C) dependent on input voltage
- (D) about 100

104. The output of a particular Op-amp increases 8 V in 12 µs. The slew rate is

- (A) 90 V/µs
- (B) 0.67 V/µs
- (C) 1.5 V/µs
- (D) None of the above

105. The input stage of an Op-amp is usually a

- (A) differential amplifier
- (B) class B push-pull amplifier
- (C) CE amplifier
- (D) swamped amplifier

106. An oscillator employs ..... feedback.

- (A) positive
- (B) negative
- (C) neither positive nor negative
- (D) Data insufficient
- 107. The piezoelectric effect in a crystal is
  - (A) a voltage developed because of mechanical stress
  - (B) a change in resistance because of temperature
  - (C) a change in frequency because of temperature
  - (D) None of the above
- 108. The Barkhausen criterion for an oscillator
  - (A) loop gain should be unity
  - (B) loop gain should be less than unity
  - (C) the phase of a feedback signal with respect to input should be  $0^{\circ}$  or  $360^{\circ}$
  - (D) Both (A) and (C)

109. An oscillator differs from an amplifier because it

- (A) has more gain
- (B) requires no input signal
- (C) requires no d.c. supply
- (D) always has the same input

- 110. The initial response when the output is not equal to input is called
  - (A) transient response
  - (B) error response
  - (C) dynamic response
  - (D) None of the above

111. ..... is a part of the human temperature control system.

- (A) Digestive system
- (B) Perspiration system
- (C) Ear
- (D) Leg movement
- 112. ..... is a closed loop system.
  - (A) Auto-pilot for an aircraft
  - (B) Direct current generator
  - (C) Car starter
  - (D) Electric switch
- 113. Transfer function of a system is used to calculate which of the following?
  - (A) The order of the system  $\searrow$
  - (B) The time constant
  - (C) The output for any given input
  - (D) The steady state gain
- 114. The relation between number of free electrons (n) in a semiconductor and temperature (T) is
  - (A)  $n \propto T$ (B)  $n \propto T^2$ (C)  $n \propto \sqrt{T}$ (D)  $n \propto T^{3/2}$
- 115. When the electrical conductivity of a semiconductor is only due to the breaking of its covalent bonds then it is said to be
  - (A) donor
  - (B) acceptor
  - (C) intrinsic
  - (D) extrinsic

- 116. P-type semiconductors are
  - (A) positively charged
  - (B) produced when Boron is added as an impurity to silicon
  - (C) produced when Phosphorous is added as an impurity to silicon
  - (D) produced when carbon is added as an impurity to germanium
- 117. Calculate the wavelength of radiation emitted by an LED made up of a semiconducting material with band gap energy 2.8 eV.
  - (A) 2.8 Å
  - (B) 4.3308 Å
  - (C) 5548.4 Å
  - (D) 4430.8 Å

# 118. The average value of current in a half wave rectifier is



119. The Value of current in the following circuit will be



What is the frequency of a photon having energy  $2.1 \times 10^{-30}$  J? 120.

- (A)  $3.1 \times 10^{13}$  Hz
- (B)  $4.1 \times 10^{13}$  Hz
- (C)  $5.1 \times 10^{13}$  Hz
- (D)  $6.1 \times 10^{13}$  Hz
- Astable multivibrator operating at 150 Hz has a discharge time of 2.5 m. 121. Find the duty cycle of the circuit.
  - (A) 50%
  - (B) 75%
  - (C) 95.99%
  - (D) 37.5%
- 122. In any AC circuit always
  - (A) apparent power is more than actual power
  - (B) reactive power is more than apparent power
  - (C) actual power is more than reactive power
  - (D) reactive power is more than actual power

#### A voltage follower 123.

- (A) has a voltage gain of 1
- (B) is noninverting
- (C) has no feedback resistor
- (D) has all of these
- Tunnel diode is basically a junction diode with 124.

  - (A) high doping in p region alone(B) high doping in p and n regions, both
  - (C) high doping in n region alone
  - (D) low doping in both p and n regions
- A thyristor can be used as 125.
  - (A) an amplifier
  - (B) a resistor
  - (C) a switch
  - (D) a power source

- 126. The control terminal (pin 5) of 555 timer IC is normally connected to ground through a capacitor (0.01  $\mu$ F). This is to
  - (A) protect the IC from inadvertent application of high voltage
  - (B) prevent false triggering by noise coupled onto the pin
  - (C) convert the trigger input to sharp pulse by differentiation
  - (D) suppress any negative triggering pulse
- 127. Gain of non-inverting amplifier is given by G =

(A) 
$$1 + \frac{R_1}{R_2}$$
  
(B)  $1 - \frac{R_1}{R_2}$   
(C)  $\frac{1 + R_1}{R_2}$   
(D)  $\frac{R_1 + R_2}{R_2}$ 

128. Stack is also known as

- (A) First in First Out Memory
- (B) Flash Memory
- (C) Last in First Out Memory
- (D) Last in Last Out Memory

129. A Nibble is equal to ..... bit(s)

- (A) 1
- (B) 2
- (C) 3
- (D) 4

130. ..... has the unit of eV

- (A) Potential difference
- (B) Energy
- (C) Charge
- (D) Current

- 131. Name the d55. Basic unit of classification is
  - (A) Kingdom
  - (B) Division
  - (C) Species
  - (D) Order
- An RF signal is amplitude modulated to a depth of 100% by a sinusoidal signal. 132. The ratio of modulated signal power to unmodulated carrier power is
  - (A) 1
  - (B) 2
  - $\frac{2}{3}$ (C)

  - $\frac{3}{2}$ (D)
- Which of the following characteristics of electrons determine 133. the current in a conductor?
  - (A) Drift velocity alone
  - (B) Thermal velocity alone
  - (C) Both drift velocity and thermal velocity
  - (D) Neither drift velocity nor thermal velocity
- Which is the relation connecting current density 'J' and conductivity  $\sigma$  of the 134. conductor, when an electric field E is applied to it?
  - (A)  $J = \sigma^2 E$
  - (B)  $J = \sigma E^2$
  - $J = \sigma E$  $(\mathbf{C})$

(D)

- 135. The power factor of an AC circuit is 0.5. What is the phase difference between voltage and current in the circuit?
  - (A)  $\pi$ (B)  $\frac{\pi}{2}$ (C)  $\frac{\pi}{4}$ (D)  $\frac{\pi}{3}$

136. The impedance of the series LCR circuit is

(A)  $Z = \sqrt{R^2 + \left(X_L - X_C\right)^2}$ 

(B) 
$$Z = \sqrt{\frac{R^2}{\left(X_L - Xc\right)^2}}$$

(C) 
$$Z = \sqrt{R^2 - \left(X_L - Xc\right)^2}$$

(D) 
$$Z = \sqrt{R^2 \times (X_L - X_C)^2}$$

## 137. Triac is a ..... switch.

- (A) Unidirectional
- (B) Mechanical
- (C) Bidirectional
- (D) Omni directional

138. The p-type emitter of the UJT is ..... doped.

- (A) lightly
- (B) heavily
- (C) not
- (D) moderately

139. Which of the following is a common application of UJT?

- (A) Amplifier
- (B) Rectifier
- (C) Multivibrator
- (D) Sawtooth generator

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140. How many pn junction does SCR have?

- (A) 2
- (B) 3
- (C) 4
- (D) 5

141. Longer the diameter of the wire ..... is its resistance.

- (A) unstable
- (B) higher
- (C) stable
- (D) lesser

142. Which following material can be used as an insulator?

- (A)  $SiO_2$
- (B) Si
- (C) Ge
- (D) Cu

143. What special type of diode capable of both oscillation and amplification?

- (A) Point contact diode
- (B) Junction diode
- (C) Zener diode
- (D) Tunnel diode
- 144. Which type of meter requires own power source?
  - (A) Voltmeter
  - (B) Ammeter
  - (C) Ohmmeter
  - (D) Wattmeter

145. The channel of a JFET is between the

- (A) gate and drain
- (B) drain and source
- (C) gate and source
- (D) input and output

- 146. Which of the following is an inductance variable type transformer?
  - (A) LVDT
  - (B) Load cell
  - (C) Thermistor
  - (D) Carbon microphone

147. The controlling parameter in MOSFET is

- (A) Vds
- (B) Ig
- (C) Vgs
- (D) Is

148. The varactor displays what useful electrical property?

- (A) Variable resistance
- (B) Variable capacitance
- (C) Variable inductance
- (D) Variable frequency
- 149. PIN diode is used as
  - (A) Amplifier
  - (B) Voltage controlled attenuator
  - (C) Rectifier
  - (D) None of the above
- 150. Potential difference between *x* and *y*



(D) -4.527 V

FINAL ANSWER KEY Subject Name: 606 ELECTRONICS									
1	B	31	A	61	В	91	C	121	D
2	A	32	C	62	B	92	D	122	A
3	C	33	C	63	В	93	A	123	D
4	В	34	В	64	D	94	C	124	В
5	A	35	В	65	D	95	В	125	C
6	В	36	C	66	В	96	C	126	В
7	D	37	В	67	В	97	C	127	C
8	D	38	С	68	А	98	C	128	С
9	C	39	C	69	В	99	В	129	D
10	C	40	В	70	В	100	A	130	В
11	Α	41	С	71	Α	101	В	131	С
12	С	42	Α	72	С	102	В	132	D
13	В	43	Α	73	C	103	Α	133	Α
14	D	44	D	74	С	104	В	134	С
15	A	45	В	75	C	105	А	135	D
16	C	46	В	76	С	106	А	136	Α
17	C	47	А	77	Α	107	Α	137	С
18	C	48	С	78	В	108	D	138	В
19	D	49	B 💊	79	С	109	В	139	D
20	D	50	A	80	D	110	А	140	В
21	В	51	В	81	В	111	В	141	D
22	D	52	С	82	С	112	А	142	Α
23	D	53	С	83	Α	113	С	143	D
24	Α	54	С	84	А	114	D	144	С
25	A	55	В	85	D	115	С	145	В
26	A	56	D	86	А	116	В	146	Α
27	A	57	В	87	В	117	D	147	С
28	A	58	В	88	В	118	А	148	В
29	C	59	D	89	B	119	В	149	B
30	A	60	A	90	B	120	B	150	B
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